TOSHIBA Field Effect Transistor Silicon N Channel MOS Type  $(\pi\text{-MOSII}^{5})$ 

# 2SK1359

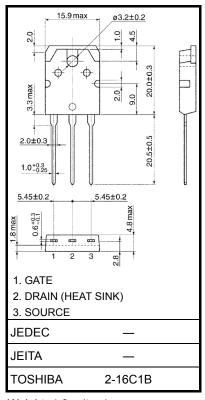
### DC-DC Converter and Motor Drive Applications

Unit: mm

 $\begin{array}{ll} \bullet & \text{Low drain-source ON resistance} & : R_{DS} \, (\text{ON}) = 3.0 \, \Omega \, (\text{typ.}) \\ \bullet & \text{High forward transfer admittance} & : |Y_{fs}| = 2.0 \, \text{S (typ.}) \\ \bullet & \text{Low leakage current} & : I_{DSS} = 300 \, \mu \text{A (max) (V}_{DS} = 800 \, \text{V}) \\ \bullet & \text{Enhancement mode} & : V_{th} = 1.5 \text{$^{\circ}$} 3.5 \, \text{V (V}_{DS} = 10 \, \text{V, I}_{D} = 1 \, \text{mA}) \\ \end{array}$ 

### **Absolute Maximum Ratings (Ta = 25°C)**

Characteris	etics	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	1000	V	
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	1000	V	
Gate-source voltage		$V_{GSS}$	±30	V	
Drain current	DC (Note 1)	I <sub>D</sub>	5	Α	
	Pulse (Note 1)	$I_{DP}$	15	Α	
Drain power dissipation	r (Tc = 25°C)	$P_{D}$	125	W	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.0	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

This transistor is an electrostatic-sensitive device.

Please handle with caution.



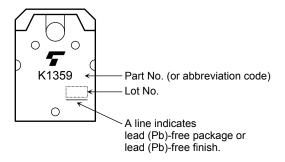
# Electrical Characteristics (Ta = 25°C)

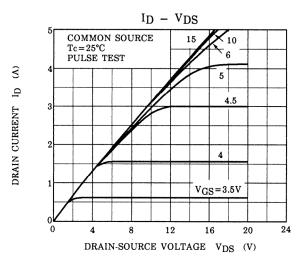
Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±25 V, V <sub>DS</sub> = 0 V	_	_	±50	nA
Drain cut-off cui	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = 800 V, V <sub>GS</sub> = 0 V	_	_	300	μΑ
Drain-source br	eakdown voltage	V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	1000	_	_	V
Gate threshold v	voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	_	3.5	V
Drain-source Ol	N resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2 A	_	3.0	3.8	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 2 A		2.0	_	S
Input capacitano	:e	C <sub>iss</sub>		_	700	_	
Reverse transfe	r capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0V, f = 1 MHz		55	_	pF
Output capacitance		Coss	]		100	_	
Switching time	Rise time	t <sub>r</sub>	$V_{GS} = \frac{10V}{0V}$ $V_{OUT}$ $R_{L}$ $V_{OUT}$ $V_{C}$ $V_$	_	18	_	- ns
	Turn-on time	t <sub>on</sub>		_	30	_	
	Fall time	t <sub>f</sub>		_	12	_	
	Turn-off time	t <sub>off</sub>	$V_{DD} = 400V$ Duty $\leq 1\%$ , $t_{W} = 10 \mu s$	_	70	_	
Total gate charge (Gate-source plus gate-drain)		Qg		_	60	_	nC
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 4 \text{ A}$	_	35	_	
Gate-drain ("miller") charge		$Q_{gd}$			25		

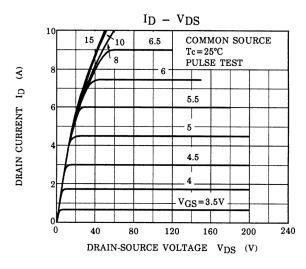
## **Source-Drain Ratings and Characteristics (Ta = 25°C)**

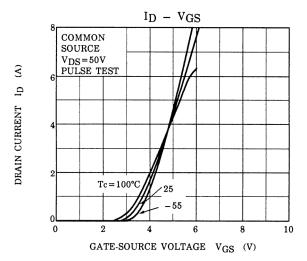
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	5	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	15	Α
Forward voltage (diode)	$V_{DSF}$	I <sub>DR</sub> = 4 A, V <sub>GS</sub> = 0 V	-		-1.9	V

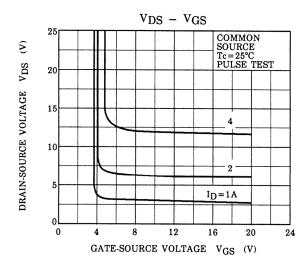
### Marking

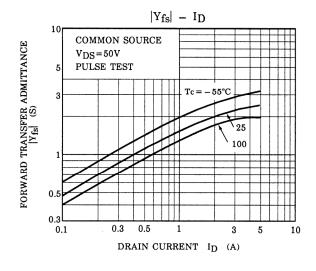


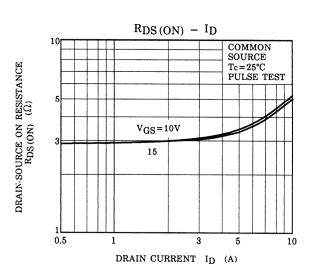




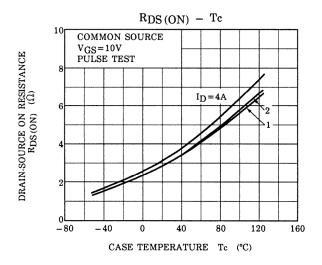


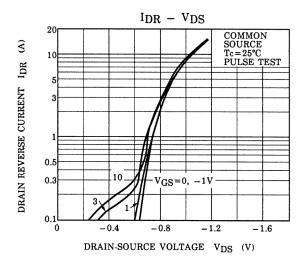


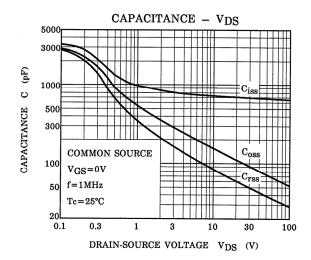


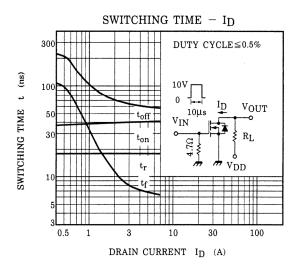


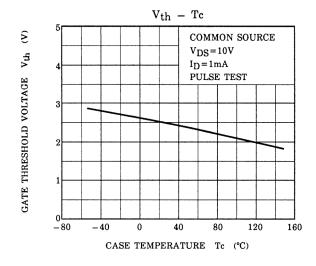
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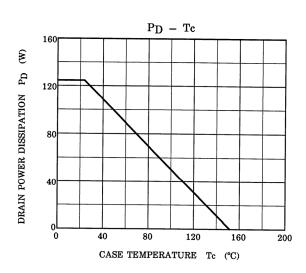


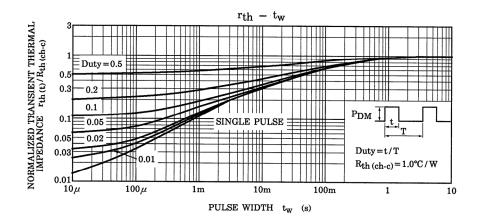


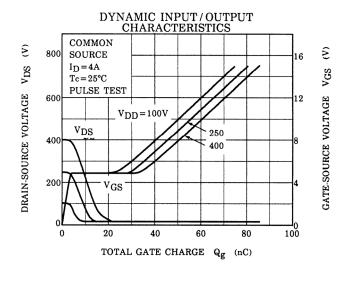


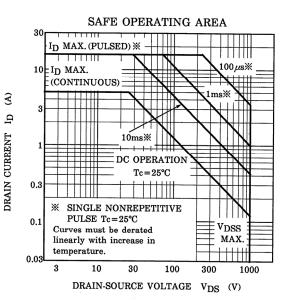












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